Quantum-ESPRESSO

PWSCF: first steps

What can I learn in this lecture ?

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```
How to run PWscf (pw.x) in self-consistent mode for Silicon
How to get the band structure of Silicon along the main symmetry directions

How to draw charge density map of Silicon in a given plane
How to deal with metals ( Aluminum )

How to deal with spin polarized systems ( Nickel )
```

What are the basic convergence parameters to have under control

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How to run PWscf (pw.x) in self-consistent mode for Silicon
How to get the band structure of Silicon along the main symmetry directions
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How to deal with metals (Aluminum, Copper)

How to deal with spin polarized systems (Nickel)

What are the basic convergence parameters to have under control

Download example file examples_pwscf_ex.tgz and unpack it.

This will create a sub-directory named examples_pwscf_ex containing several files.

Move to examples_pwscf_ex and check its content

```
prompt> cd examples_pwscf_ex

prompt> ls
al.g.12 al.m-p.12 al.m-v.12 al.scf.in run_si_eos si.pp_rho
al.g.16 al.m-p.16 al.m-v.16 bands.in si.etot_vs_ecut si.scf.in
al.g.6 al.m-p.6 al.m-v.6 k-point-path si.etot_vs_nks
al.g.8 al.m-p.8 al.m-v.8 ni.scf.in si.plotrho.in
```

Self-consistent calculation for Silicon in the diamond structure

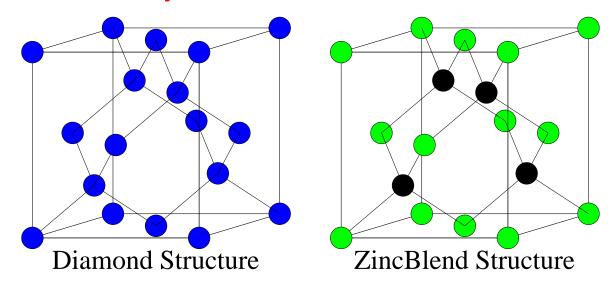
Edit input file si.scf.in

Notice that it is an scf calculation (default value)

Write the appropriate values for outdir and pseudo_dir

Check that these directories exist, have read/write permission and that pseudo_dir contains pseudopotential file Si.vbc.UPF for Silicon

How the crystal structure is defined?



check in the input file

How the Bravais lattice is selected?

How many and which parameters are needed to completely define Bravais lattice geometry?

How many atoms in the unit cell?

How many different atomic species?

Which ones?

Where the atoms are located in the unit cell?

Brillouin zone sampling

BZ sampling is performed using 2 Chadi-Cohen special points for the fcc lattice.

For an introduction to special points techniques see for instance A. Baldereschi, *Phys. Rev. B* **7**, 5212 (1973).

D.J. Chadi e M.L. Cohen, *Phys. Rev. B* 8, 5747 (1973).

H.J. Monkhorst e J.D. Pack, *Phys. Rev. B* 13, 5188 (1976).

check in the input file how k-points are provided manually

k-points are given (default) in cartesian coordinates in unit of 2pi/celldm(1)

k-point weights need not add-up to 1, they are later normalized

run pw.x code

prompt> espresso_dir/bin/pw.x < si.scf.in > si.scf.out

look at outdir and its content

prompt> ls /scratch/my_name/espresso
silicon.save silicon.wfc

examine output file and look how convergence proceeds

```
prompt> grep -e 'total energy' -e estimate si.scf.out
                                  -15.78885161 ryd
    total energy
    estimated scf accuracy
                                    0.06378063 ryd
                              = -15.79407709 ryd
    total energy
    estimated scf accuracy
                                    0.00231243 ryd
                                  -15.79448017 ryd
    total energy
    estimated scf accuracy
                                    0.00006733 ryd
                              <
                                  -15.79449452 ryd
    total energy
                              =
    estimated scf accuracy
                                    0.00000619 ryd
                              = -15.79449556 ryd
    total energy
                                    0.00000006 ryd
    estimated scf accuracy
                              <
```

Bands at high-symmetry points in silicon:

Copy file si.scf.in to si.nscf.in Edit file si.nscf.in and set it for a non-self-consistent band calculation in three high symmetry points: $\Gamma = (0,0,0), X=(1,0,0)\frac{2\pi}{a}$ and $L=(1/2,1/2,1/2)\frac{2\pi}{a}$ define calculation='bands' in CONTROL namelist define nbnd=8 (4 valence + 4 conduction) in SYSTEM namelis define the three k-points in the K_POINTS card K_POINTS 3 0.0 0.0 0.0 1.0 0.0 0.0 2 WEIGHTS ARE MEANINGLESS IN NSCF CALCS

DO NOT MODIFY outdir or prefix,
DO NOT REMOVE files from scratch area

3

0.5 0.5 0.5

Bands at high-symmetry points in silicon:

```
run pw.x code
prompt> espresso_dir/bin/pw.x < si.nscf.in > si.nscf.out
look at the output
```

```
how many iteration have been performed?
which potential is used in the diagonalization?
which wfcs are used as initial guess?
is the charge density and/or the total energy computed?
```

Band structure calculation for silicon:

Copy file si.nscf.in to si.bands.in

Edit file si.bands.in and modify the k-point list so as to perform a path in the BZ along Λ , Δ and Σ directions as defined by in file k-point-path run pw.x code

prompt> espresso_dir/bin/pw.x < si.bands.in > si.bands.out

Now collect band results for plotting:

edit file bands.in in order to define the proper value for outdir and then run bands.x

prompt> espresso_dir/bin/bands.x < bands.in > bands.out

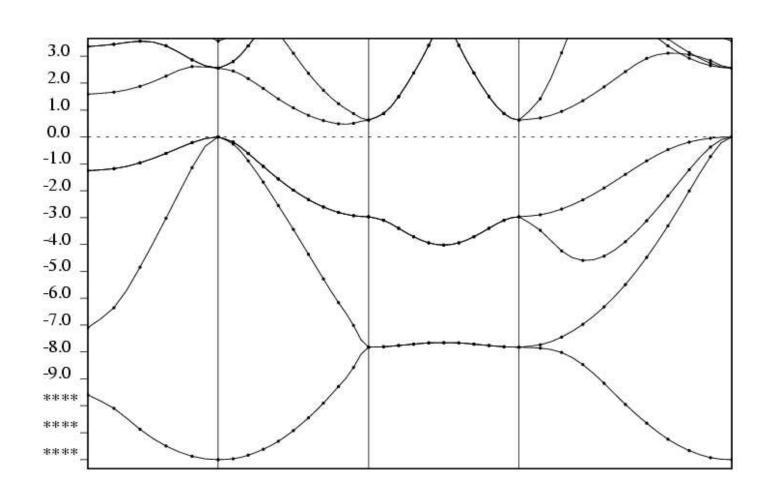
verify the content of file bands.out and bands.dat, notice the value of the valence band maximum at Γ and then run plotband.x interactively prompt> espresso_dir/bin/plotband.x

Band structure calculation for silicon:

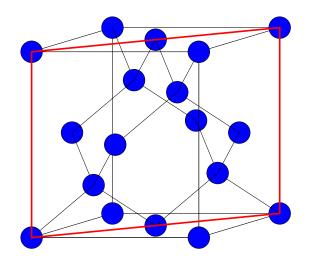
```
prompt> espresso_dir/bin/plotband.x
input file > bands.dat
Reading 8 bands at 36 k-points
Range: -5.6680 \ 16.4950eV Emin, Emax > -6.0 \ 10.0
high-symmetry point: 0.5000 0.5000 0.5000
high-symmetry point: 0.0000 0.0000 0.0000
high-symmetry point: 0.0000 0.0000 1.0000
high-symmetry point: 0.0000 1.0000 1.0000
high-symmetry point: 0.0000 0.0000 0.0000
output file (xmgr) > si.bands.xmgr
bands in xmgr format written to file si.bands.xmgr
output file (ps) > si.bands.ps
Efermi > 6.337
deltaE, reference E (for tics) 1.0, 6.337
bands in PostScript format written to file si.bands.ps
```

Band structure calculation for silicon:

prompt> ghostview si.bands.ps



Charge density plot for silicon in the [1-10] plane:



Edit file si.pp_rho.in to properly define outdir and then run the postprocessing code (pp.x) to extract the charge density (plotnum=0)

prompt> espresso_dir/bin/pp.x < si.pp_rho.in</pre>

prompt> espresso_dir/bin/pp.x < si.pp_rho.in
 Program POST-PROC v.3.1 starts ...
 Today is 26May2006 at 20:17:44</pre>

nbndx = 8 nbnd = 8 natomwfc = 8 npwx = 200nelec = 8.00 nkb = 8 ngl = 43

Calling punch_plot, plot_num = 0
Writing data to file sicharge
Reading header from file sicharge
Reading data from file sicharge

Writing data to be plotted to file si.rho.dat
Min, Max, imaginary charge: 0.002838 0.093121 0.000000
Plot Type: 2D contour Output format: plotrho.x

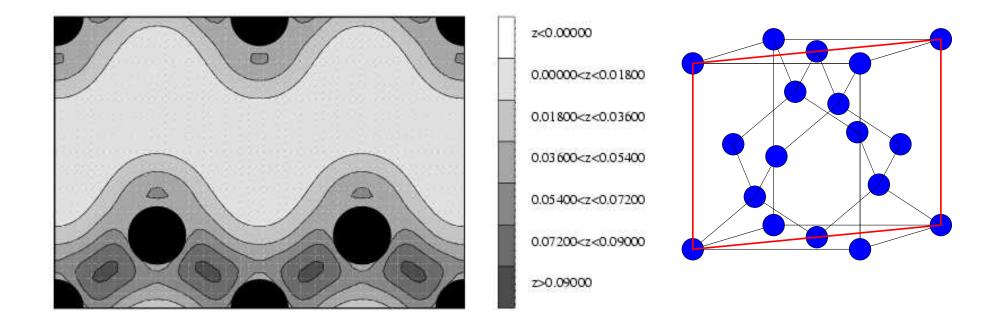
Charge density plot for silicon in the [1-10] plane:

```
run plotrho.x produce the plot
prompt> espresso_dir/bin/plotrho.x
input file > si.rho.dat
ro : 0.0000 0.0000 0.0000
tau1: 1.0000 1.0000 0.0000
tau2: 0.0000 0.0000 1.0000
read 2 atomic positions
output file > si.rho.ps
Read 56 * 40 grid
Logarithmic scale (y/n)? > n
Bounds: 0.002839 0.093110
min, max, # of levels > 0 0.09 6
```

Charge density plot for silicon in the [1-10] plane:

prompt> ghostview si.rho.ps

si.rho.dat



Convergence w.r.t. kinetic energy cutoff:

Clean outdir;

Change value of ecutwfc in si.scf.in input file to 16, 20, 24 Ry;

Run pw.x again and again and complete the data in si_etot_vs_ecut;

Plot the data in si_etot_vs_ecut and notice the monotonic convergence.

Convergence w.r.t to cutoff is a property of the pseudopotential

Convergence w.r.t. k-points:

```
Clean outdir;
```

```
Edit si.scf.in and set back ecutwfc to 12 Ryd;
```

```
Change k-points using automatic grid with nk=2,4,6 K_POINTS automatic
```

2 2 2 1 1 1

Run pw.x and complete entries in file si_etot_vs_nks;

Convergence is not necessarily monotonic;

There is no variational principle w.r.t. k-points number

A metallic example: Aluminum

Clean outdir;

Edit file al.scf.in and define outdir and pseudo_dir;

Notice the use of variables occupations, smearing, degauss;

```
Run pw.x
prompt> espresso_dir/bin/pw.x < al.scf.in > al.scf.out
```

Notice in output file that nbnd is automatically set to a value larger than nelec/2 and that Efermi is computed.

Convergence with respect to degauss/smearing ...

Edit file al.scf.in and vary variables smearing

[gaussian (g), marzari-vanderbilt (m-v), methfessel-paxton (m-p)] and degauss [0.06, 0.07, 0.08, 0.09, 0.10] in order to complete entries of al.g.6, al.m-v.6, al.m-p.6 files

Plot the content of al.g.6, al.g.8, al.g.12, al.g.16, and similarly for m-v and m-p

Notice that for metals convergence is SLOW

It can be improved by using m-v or m-p.

A magnetic example: Nickel

Clean outdir;

Edit file ni.scf.in and define outdir and pseudo_dir;

Notice use of variables nspin and starting_magnetization.

Notice that this is a metallic calculation.

Nickel pseudopotential is US-PP: ecutrho $> 4 \times$ ecutwfc

Run pw.x
prompt> espresso_dir/bin/pw.x < ni.scf.in > ni.scf.out

Notice that the number of k-points is doubled w.r.t non-magnetic case

Notice different number of calls and timing of cft3 and cft3s routines. Why it is convenient to introduce a different cutoff for wfcs and rho?

Equation of State: Silicon

edit run_si_eos and define variables espresso_dir, pseudo_dir and outdir.

```
prompt> sh run_si_eos
```

Notice how file si.etot_vs_alat is created at the end of script file

```
Plot content of si.etot_vs_alat
  prompt> gnuplot
gnuplot> plot "si.etot_vs_alat" w l
```

HOMEWORK

Modifiy the script and change cutoff, k-points and so on.

Verify that Energy_vs_alat curves are shifted down rather uniformly with increasing cutoff and are not stronly dependend on k-points.

Structural properties and energy differences concerge faster that total energies.

Compute the equation of state of Ni.

